L Number	Hits	Search Text	DB	Time stamp
1	0	(gate adj array) and (esd adj implantation)	USPAT; US-PGPUB;	2004/04/12
	:		EPO; JPO; DERWENT;	
2	0	(gate adj array) and (esd adj diffusion)	IBM_TDB USPAT;	2004/04/12
			US-PGPUB; EPO; JPO;	15:53
			DERWENT; IBM_TDB	
3	4	esd adj diffusion	USPAT; US-PGPUB;	2004/04/12 15:55
			EPO; JPO; DERWENT;	
4	52	esd adj implant	IBM_TDB USPAT; US-PGPUB;	2004/04/12
			EPO; JPO; DERWENT;	10.04
5	0	surge adj protection adj (implant or	IBM_TDB USPAT;	2004/04/12
		implantaion or diffusion or dopant)	US-PGPUB; EPO; JPO;	16:05
		·	DERWENT; IBM TDB	
6	65	(esd or (electrostatic adj discharge)) adj (implant or implantaion or diffusion	USPAT; US-PGPUB;	2004/04/12 16:19
		or dopant)	EPO; JPO; DERWENT;	
7	1	(voltage adj protection) adj (implant or implantaion or diffusion or dopant)	IBM_TDB USPAT; US-PGPUB;	2004/04/12
		implantation of diffusion of dopant)	EPO; JPO; DERWENT;	17:02
8	2	20020076876.pn.	IBM_TDB USPAT;	2004/04/12
		•	US-PGPUB; EPO; JPO;	17:04
			DERWENT; IBM_TDB	
9	2	6008080.pn.	USPAT; US-PGPUB;	2004/04/12 18:18
			EPO; JPO; DERWENT;	
10	2	6268256.pn.	IBM_TDB USPAT; US-PGPUB;	2004/04/12 18:18
			EPO; JPO; DERWENT;	
_	2	5559352.pn.	IBM_TDB USPAT;	2004/04/07
			US-PGPUB; EPO; JPO;	18:17
	2	20030141551.pn.	DERWENT; IBM_TDB USPAT;	2004/04/07
	2	20030141331.pm.	US-PGPUB; EPO; JPO;	18:38
			DERWENT; IBM TDB	
*	0	(esd adj (layer or region or film)) adj drain	USPĀT; US-PGPUB;	2004/04/07 18:40
			EPO; JPO; DERWENT;	
-	0	((electro adj static adj discharge) adj	IBM_TDB USPAT;	2004/04/07
		(layer or region or film)) adj drain	US-PGPUB; EPO; JPO; DERWENT;	18:40
			IBM TDB	

Search History 4/12/04 7:26:54 PM

-	0	((electrostatic adj discharge) adj (layer or region or film)) adj drain	USPAT; US-PGPUB; EPO; JPO;	2004/04/07 18:40
			DERWENT; IBM TDB	
_	0	((breakdown adj enhanced) adj (layer or region or film)) adj drain	USPAT; US-PGPUB; EPO; JPO;	2004/04/07
	3	(esd adj (layer or region or film)) near	DERWENT; IBM_TDB USPAT;	2004/04/07
	3	drain	US-PGPUB; EPO; JPO; DERWENT;	18:41
-	0	((electro adj static adj discharge) adj (layer or region or film)) near drain	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/07 18:41
-	0	((electrostatic adj discharge) adj (layer or region or film)) near drain	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/04/07 18:42
-	0	((breakdown adj enhanced) adj (layer or region or film)) near drain	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/04/07 18:42
-	34	(esd adj (layer or region or film)) with	DERWENT; IBM_TDB USPAT;	2004/04/07
		drain	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	
-	0	((electro adj static adj discharge) adj (layer or region or film)) with drain	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/07 18:50
-	2	((electrostatic adj discharge) adj (layer or region or film)) with drain	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/07 18:47
-	2	((breakdown adj enhanced) adj (layer or region or film)) with drain	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/04/07 18:47
_	29	(esd adj (layer or region or film)) with source	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/04/07 18:46
-	0	((electro adj static adj discharge) adj (layer or region or film)) with source	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/04/07
-	3	((electrostatic adj discharge) adj (layer or region or film)) with source	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2004/04/07
_	1	((breakdown adj enhanced) adj (layer or	DERWENT; IBM_TDB USPAT;	2004/04/07
		region or film)) with source	US-PGPUB; EPO; JPO; DERWENT; IBM TDB	18:47

	61		USPAT;	2004/04/07
<del>,                                   </del>	61	((electro adj static adj discharge) or		19:02
		esd or (electrostatic adj discharge) or	US-PGPUB;	19:02
		breakdown or enhance) near2 formed near2	EPO; JPO;	
		(source or drain)	DERWENT;	
	!		IBM_TDB	
-	76	, ,, ,, ,, ,, ,, ,, ,,	USPAT;	2004/04/07
	ļ	film or region)) and esd	US-PGPUB;	19:03
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	79	((breakdown or enhanced) adj (layer or	USPAT;	2004/04/07
		film or region)) and esd	US-PGPUB;	19:04
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	877	(body adj region) and (drift)	USPAT;	2004/04/07
			US-PGPUB;	19:09
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	2471	(breakdown or enhanced) adj (layer or	USPAT;	2004/04/07
		film or region)	US-PGPUB;	19:09
1			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	10	(reduce adj breakdown adj voltage) with	USPĀT;	2004/04/07
		drain with esd	US-PGPUB;	19:56
		· · · · · · · ·	EPO; JPO;	
			DERWENT;	
			IBM TDB	]
_	35	esd adj implantation	USPAT;	2004/04/12
			US-PGPUB;	15:52
			EPO; JPO;	
			DERWENT;	
]			IBM TDB	
	1		1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	L